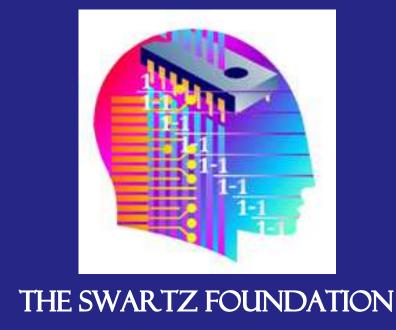


# A memory frontier for complex synapses

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#### Background

#### Storage capacity of synaptic memory

A classical perceptron, when used as a recognition memory device, has a memory capacity proportional to the number of synapses, N. However, this requires synapses to have a dynamic range also  $\propto N$ .

If synaptic efficacies are limited to a fixed dynamic range, this introduces a strong tradeoff between learning and forgetting due to new memories overwriting old. If we wish to store new memories rapidly, then memory capacity is  $\mathcal{O}(\log N)$ .

[Coba et al. (2009)]

[Amit and Fusi (1992), Amit and Fusi (1994)]

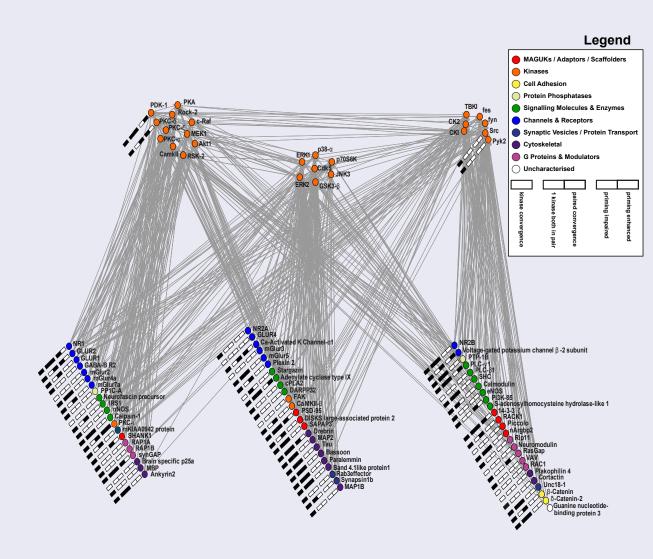
To circumvent this tradeoff, it is essential to enlarge our theoretical conception of a synapse as a single number.

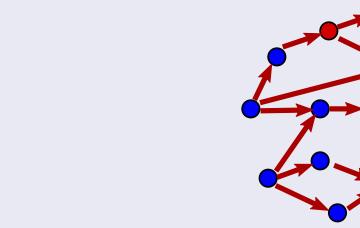
#### Complex synapses

In reality, a synapse is a complex dynamical system.

We will describe a synapse by stochastic processes on a finite number of states, M.

Potentiation and depression cause transitions between these states.

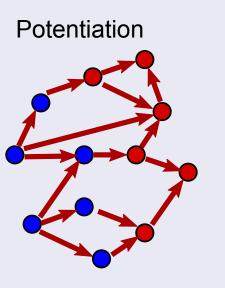


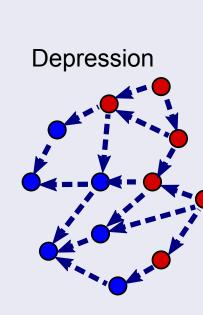


Possible molecular states

strong state

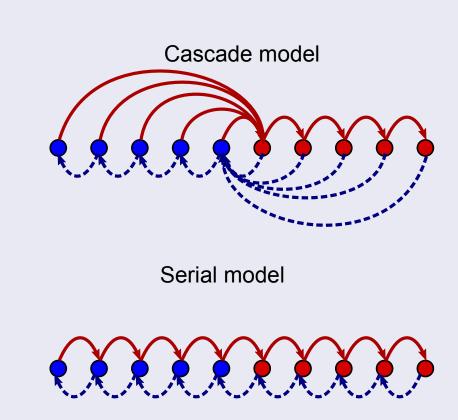
weak state

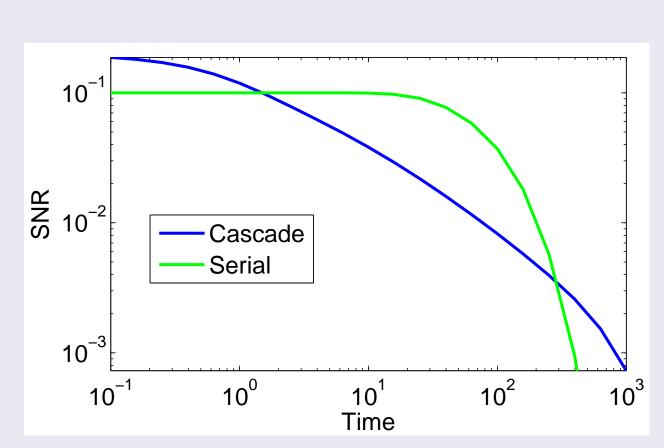




## Cascade and serial models

Two example models of complex synapses with different memory storage properties.





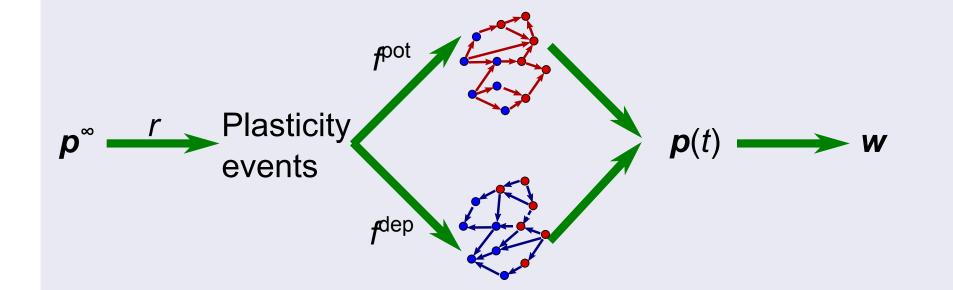
#### [Fusi et al. (2005), Leibold and Kempter (2008)]

## Questions

- Can we understand the space of all possible synaptic models?
- How does the structure (topology) of a synaptic model affect its function (memory curve)?
- How does synaptic complexity (number of states) extend the frontiers of possibility for memory?
- Which synaptic state transition topologies maximize measures of memory?

#### Framework

#### Synaptic state transition models



#### Assumptions:

- Candidate plasticity events occur independently at each synapse,
- Each synapse responds with the same state-dependent rules,
- ullet Synaptic weight takes only two values,  $\pm 1$ .

[Fusi et al. (2005), Fusi and Abbott (2007), Barrett and van Rossum (2008)]

#### Memory curve

We use the ideal observer approach: read synaptic weights directly. This is an upper bound on what could be read from network activity. To measure memory quality, let  $\vec{w}$  be an N-element vector of synaptic strengths,

$$\mathsf{SNR}(t) = \frac{\langle \vec{w}_{\mathsf{ideal}} \cdot \vec{w}(t) \rangle - \langle \vec{w}_{\mathsf{ideal}} \cdot \vec{w}(\infty) \rangle}{\sqrt{\mathsf{Var} \left( \vec{w}_{\mathsf{ideal}} \cdot \vec{w}(\infty) \right)}}.$$

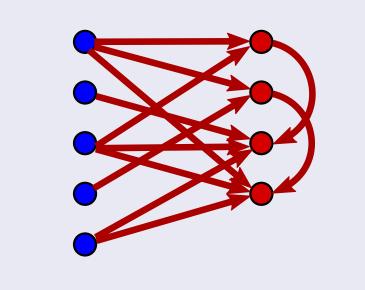
## Upper bounds on performance

## Initial SNR bound

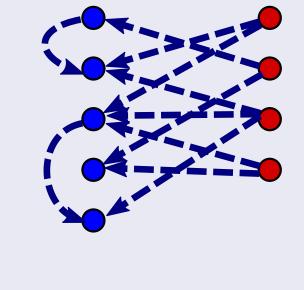
Initial SNR is closely related to equilibrium flux between strong & weak states

$$\mathsf{SNR}(0) \leq \frac{4\sqrt{N}}{r} \Phi_{-+}.$$

Maximized when potentiation guarantees  $\vec{w} \rightarrow$  strong, depression guarantees  $\vec{w} \rightarrow$  weak.



 $SNR(t) = \sqrt{N} (4f^{pot}f^{dep}) e^{-rt}$ .



[Kemeny and Snell (1960)]



## Maximal initial SNR: $SNR(0) \le \sqrt{N}$ .

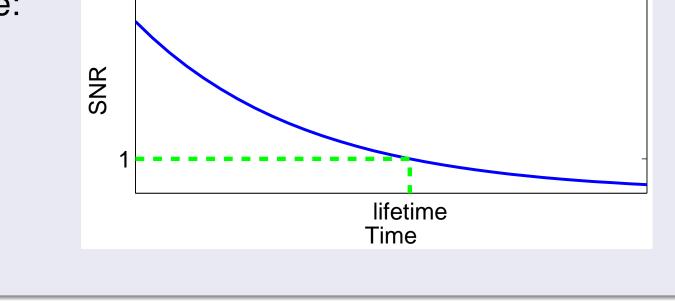
→ Equivalent to two-state model

#### Area bound

The memory lifetime is bounded by the area under the SNR curve:  $SNR(lifetime) = 1 \implies lifetime < A$ .

We can show that this area has an upper bound:

 $A \le \sqrt{N}(M-1)/r$ . This is saturated by a transition diagram with the serial topology.



## Proof: Impose an ordering on the states

Let  $T_{ij}$  be the mean first passage time from state i to state j. The following quantity

$$\eta = \sum_{\pmb{i}} \mathsf{T}_{\pmb{i}\pmb{j}} \mathsf{p}_{\pmb{j}}^{\infty},$$

is independent of the initial state *i*. It is known as Kemeney's constant.

We define:

$$\eta_{\pmb{i}}^+ = \sum_{\pmb{j} \in \mathsf{strong}} \mathsf{T}_{\pmb{i}\pmb{j}} \mathsf{p}_{\pmb{j}}^\infty, \qquad \eta_{\pmb{i}}^- = \sum_{\pmb{j} \in \mathsf{weak}} \mathsf{T}_{\pmb{i}\pmb{j}} \mathsf{p}_{\pmb{j}}^\infty.$$

These measure "distance" to the strong/weak states. They can be used to arrange the states in an order (increasing  $\eta^-$  or decreasing  $\eta^+$ ).

#### Maximal area

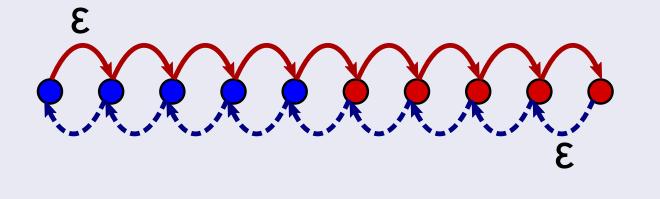
Given any synaptic model, we can construct one with a linear chain topology that has

- the same state order,
- the same equilibrium distribution,a larger area.
- ium distribution,

Uses a deformation that reduces "shortcut" transition probabilities and increases the bypassed "direct" ones. The area of this model is  $\frac{2\sqrt{N}}{2}$ 

 $A = \frac{2\sqrt{N}}{r} \sum_{k} \mathbf{p}_{k}^{\infty} |k - \langle k \rangle|.$ 

This is maximized when the equilibrium probability distribution is concentrated at both ends.



In the limit  $\varepsilon \to 0$ .

## Eigenmode decomposition

We can split the system along eigenvectors of the stochastic forgetting process:

$$SNR(t) = \sqrt{N} \sum_{a} \mathcal{I}_{a} e^{-rt/\tau_{a}}.$$

The upper bounds on initial SNR and area tell us:

$$\sum_{a} \mathcal{I}_{a} \leq 1$$
,

$$\sum_{\mathbf{a}} \mathcal{I}_{\mathbf{a}} \tau_{\mathbf{a}} \leq \mathbf{M} - \mathbf{1}.$$

- What are the implications for the full memory curve?
- Are there any other important constraints?

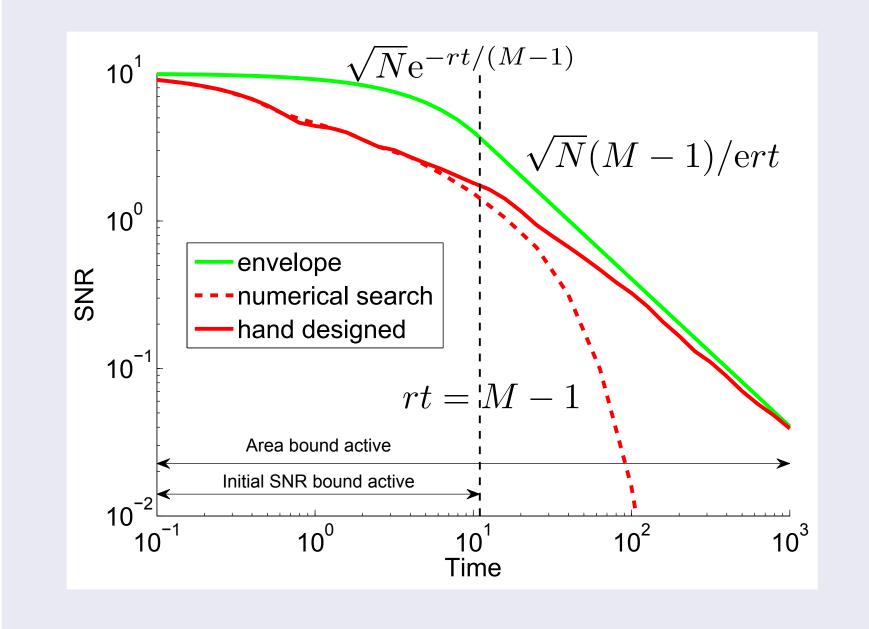
## The memory envelope

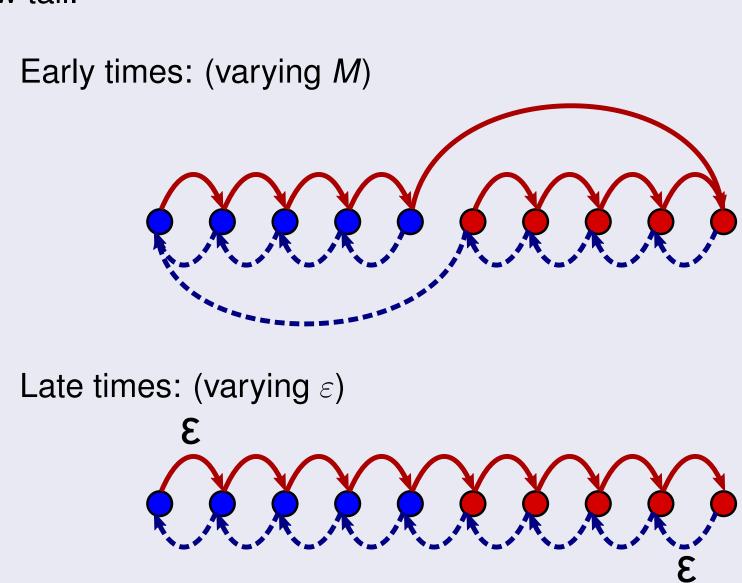
## The frontiers of possibility: a maximal SNR curve

Markovian learning and forgetting  $\implies$  SNR is a sum of decaying exponentials.

Optimizing the SNR at one time,  $t_0$ , over the space of such curves, subject to upper bounds on initial SNR and area, yields an upper bound on SNR at  $t_0$  for any synaptic model. The resulting optimal memory curve is a single exponential (optimizing at two or more well separated times requires multiple exponentials).

Varying  $t_0$  yields a memory envelope curve with a power law tail.



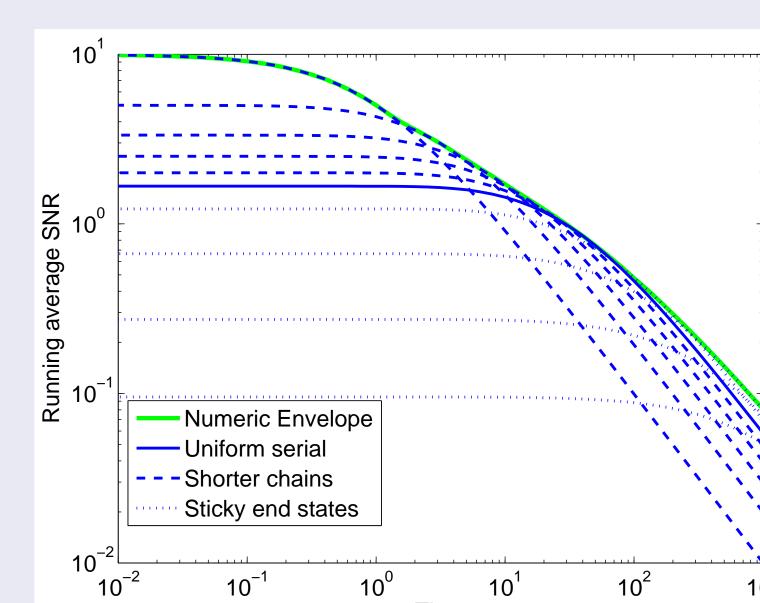


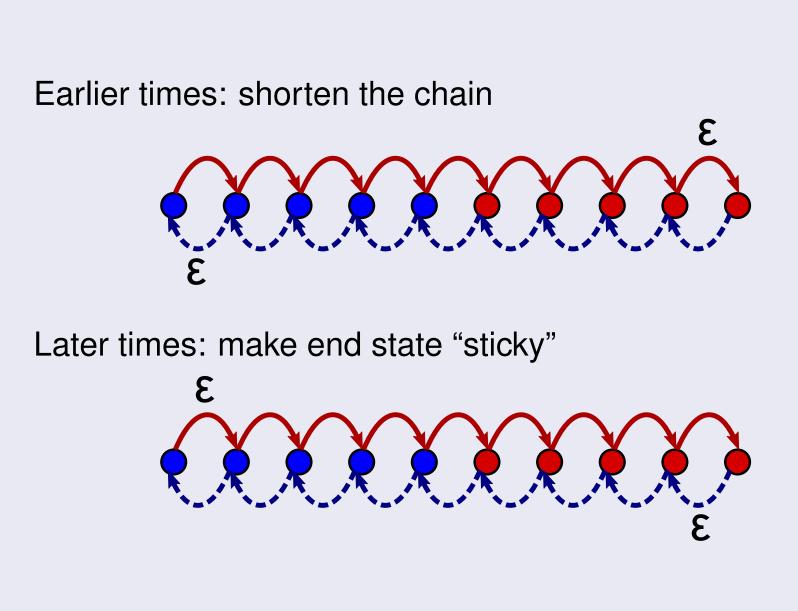
## Envelope for running average memory curve

We define the running average SNR:

$$\widehat{\mathsf{SNR}}(\tau) = \frac{1}{\tau} \int_0^\infty \! \mathrm{d}t \, \mathrm{e}^{-t/\tau} \; \mathsf{SNR}(t) \sim \frac{1}{\tau} \int_0^\tau \! \mathrm{d}t \; \mathsf{SNR}(t)$$

For any  $\tau$ , this is maximized by a model with the serial topology.





## Summary

- We have formulated a general theory of learning and memory with complex synapses.
- We can impose an order on the internal states of a synapse through the theory of first passage times.
- The area under the memory curve of any synaptic transition diagram cannot exceed that of a linear chain with the same equilibrium probability distribution.
- We find a memory envelope: a single curve that cannot be exceeded by the memory curve of *any* synaptic model.
- Synaptic complexity (M internal states) raises the memory envelope linearly in M for times  $> \mathcal{O}(M)$ .

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